

# PDTC323TK

NPN 500 mA, 15 V resistor-equipped transistor;  
R1 = 2.2 kΩ, R2 = open

Rev. 02 — 16 November 2009

Product data sheet

## 1. Product profile

### 1.1 General description

500 mA NPN Resistor-Equipped Transistor (RET) in a small SOT346 (SC-59A) SMD plastic package.

PNP complement: PDTA323TK.

### 1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- 500 mA output current capability
- Reduces component count
- Reduces pick and place costs

### 1.3 Applications

- Digital application in automotive and industrial segments
- Controlling IC inputs
- Cost saving alternative for BC817 series in digital applications
- Switching loads

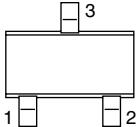
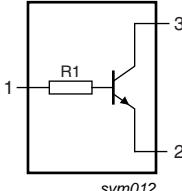
### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	15	V
I <sub>O</sub>	output current		-	-	500	mA
R <sub>1</sub>	bias resistor 1 (input)		1.54	2.2	2.86	kΩ

## 2. Pinning information

**Table 2. Pinning**

Pin	Description	Simplified outline	Symbol
1	input (base)		
2	GND (emitter)		
3	output (collector)		 sym012

## 3. Ordering information

**Table 3. Ordering information**

Type number	Package			Version
	Name	Description		
PDT <sup>C</sup> 323TK	SC-59A	plastic surface mounted package; 3 leads		SOT346

## 4. Marking

**Table 4. Marking codes**

Type number	Marking code
PDT <sup>C</sup> 323TK	57

## 5. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit	
V <sub>CBO</sub>	collector-base voltage	open emitter	-	30	V	
V <sub>CEO</sub>	collector-emitter voltage	open base	-	15	V	
V <sub>EBO</sub>	emitter-base voltage	open collector	-	5	V	
V <sub>I</sub>	input voltage					
	positive		-	+12	V	
	negative		-	-5	V	
I <sub>O</sub>	output current		-	500	mA	
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C	
T <sub>j</sub>	junction temperature		-	150	°C	
T <sub>amb</sub>	ambient temperature		-65	+150	°C	

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

## 6. Thermal characteristics

**Table 6. Thermal characteristics**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	-	500 K/W

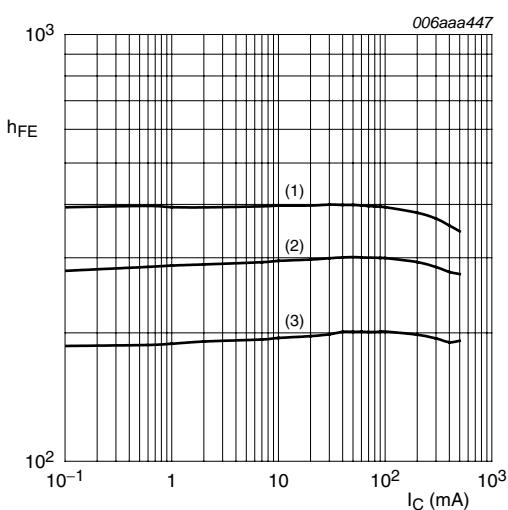
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

## 7. Characteristics

**Table 7. Characteristics**

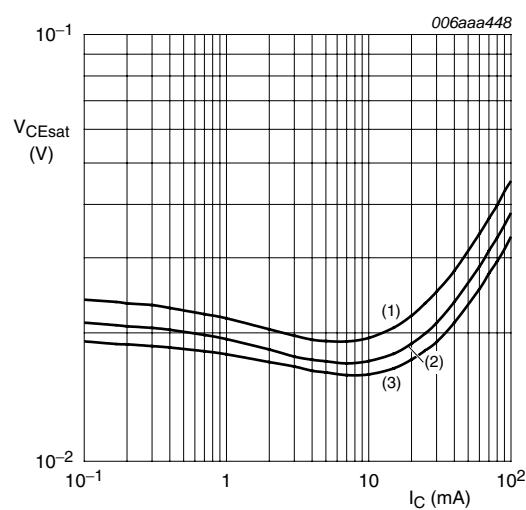
T<sub>amb</sub> = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I <sub>CB0</sub>	collector-base cut-off current	V <sub>CB</sub> = 30 V; I <sub>E</sub> = 0 A	-	-	100	nA
I <sub>CEO</sub>	collector-emitter cut-off current	V <sub>CE</sub> = 15 V; I <sub>B</sub> = 0 A	-	-	0.5	μA
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0 A	-	-	100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 50 mA	100	300	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = 50 mA; I <sub>B</sub> = 2.5 mA	-	25	80	V
R <sub>1</sub>	bias resistor 1 (input)		1.54	2.2	2.86	kΩ
C <sub>c</sub>	collector capacitance	V <sub>CB</sub> = 10 V; I <sub>E</sub> = I <sub>e</sub> = 0 A; f = 1 MHz	-	7	-	pF



$V_{CE} = 5$  V  
(1)  $T_{amb} = 100$  °C  
(2)  $T_{amb} = 25$  °C  
(3)  $T_{amb} = -40$  °C

**Fig 1.** DC current gain as a function of collector current; typical values



$I_C/I_B = 20$   
(1)  $T_{amb} = 100$  °C  
(2)  $T_{amb} = 25$  °C  
(3)  $T_{amb} = -40$  °C

**Fig 2.** Collector-emitter saturation voltage as a function of collector current; typical values

## 8. Package outline

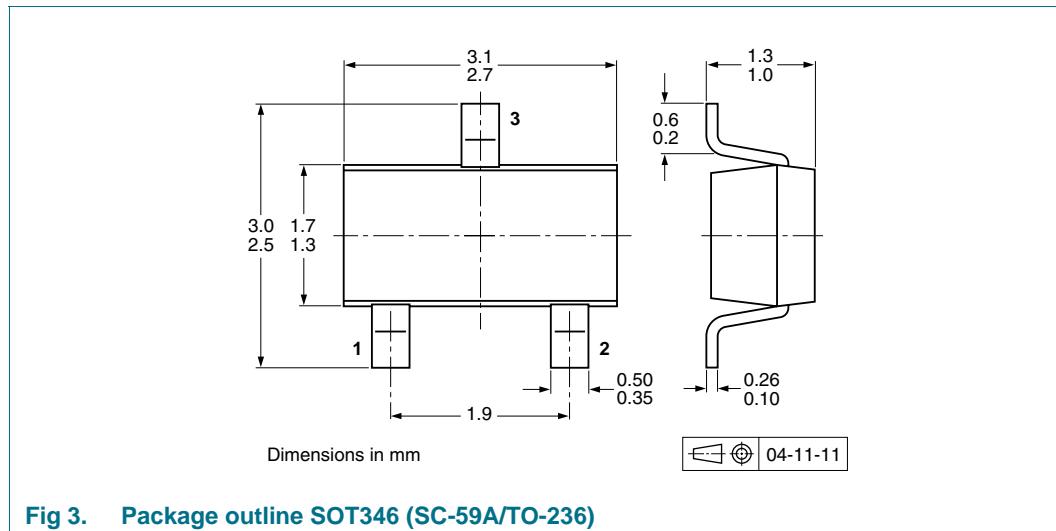


Fig 3. Package outline SOT346 (SC-59A/TO-236)

## 9. Packing information

**Table 8. Packing methods**

The indicated -xxx are the last three digits of the 12NC ordering code.<sup>[1]</sup>

Type number	Package	Description	Packing quantity	
PDT323TK	SOT346	4 mm pitch, 8 mm tape and reel	3000	10000

[1] For further information and the availability of packing methods, see [Section 12](#).

## 10. Revision history

**Table 9. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
PDT <sup>C</sup> 323TK_2	20091116	Product data sheet	-	PDT <sup>C</sup> 323TK_1
Modifications:	<ul style="list-style-type: none"><li>This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content.</li></ul>			
PDT <sup>C</sup> 323TK_1	20050603	Product data sheet	-	-

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### 11.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Date of release: 16 November 2009  
Document identifier: PDT<sup>C</sup>323TK\_2